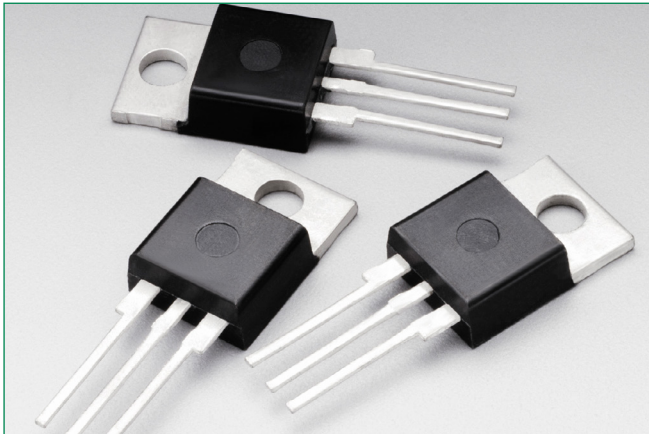


# 2N6344

Surface Mount – 600-800V



## Description

The 2N6344 is designed primarily for full-wave AC control applications, such as light dimmers, motor controls, heating controls and power supplies; or wherever full-wave silicon gate controlled solid-state devices are needed. Triac type thyristors switch from a blocking to a conducting state for either polarity of applied anode voltage with positive or negative gate triggering.

## Features

- Blocking Voltage to 800 V
- All Diffused and Glass Passivated Junctions for Greater Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Construction for Low Thermal Resistance, High Heat Dissipation and Durability
- Gate Triggering Guaranteed in all Four Quadrants
- For 400 Hz Operation, Consult Factory
- Pb-Free Package is Available

## Additional Information



Resources

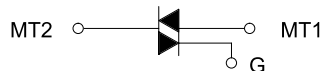
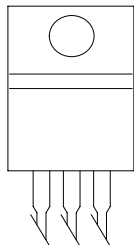
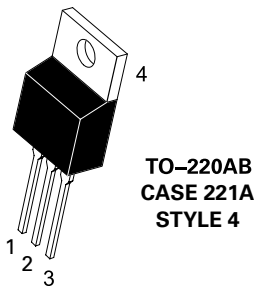


Accessories



Samples

## Pin Out



**2N6344**

Surface Mount – 600-800V

**Maximum Ratings and Thermal Characteristics** ( $T_J = 25^\circ\text{C}$  unless otherwise noted)

Rating	Symbol	Value	Unit
*Peak Repetitive Off-State Voltage (Note 1) ( $T_J = -40$ to $110^\circ\text{C}$ , Sine Wave, 50 to 60 Hz, Gate Open) 2N6344 2N6349	$V_{DRM}$ $V_{RRM}$	600 800	V
† On-State RMS Current ( $T_C = +80^\circ\text{C}$ ) Full Cycle Sine Wave 50 to 60 Hz ( $T_C = +90^\circ\text{C}$ )	$I_{T(RMS)}$	8.0 4.0	A
† Peak Non-Repetitive Surge Current (One Full Cycle, Sine Wave 60 Hz, $T_C = +25^\circ\text{C}$ ) Preceded and followed by rated current	$I_{TSM}$	100	A
Circuit Fusing Considerations ( $t = 8.3$ ms)	$I_t^2$	40	$\text{A}^2\text{s}$
†Peak Gate Power ( $T_C = +80^\circ\text{C}$ , Pulse Width = $2\ \mu\text{s}$ )	$P_{GM}$	20	W
†Average Gate Power ( $T_C = +80^\circ\text{C}$ , $t = 8.3$ ms)	$P_{G(AV)}$	0.5	W
†Peak Gate Current ( $T_C = +80^\circ\text{C}$ , Pulse Width = $2.0\ \mu\text{s}$ )	$I_{GM}$	2.0	A
†Peak Gate Voltage ( $T_C = +80^\circ\text{C}$ , Pulse Width = $2.0\ \mu\text{s}$ )	$V_{GM}$	10	V
†Operating Junction Temperature Range	$T_J$	-40 to +125	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-40 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

† Indicates JEDEC Registered Data.

1.  $V_{DRM}$  and  $V_{RRM}$  for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

**Thermal Characteristics**

Rating	Symbol	Value	Unit
† Thermal Resistance, Junction to Case	$R_{\theta JC}$	2.2	$^\circ\text{C}/\text{W}$
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	$T_L$	260	$^\circ\text{C}$

† Indicates JEDEC Registered Data.

**Electrical Characteristics - OFF** ( $T_C = 25^\circ\text{C}$  unless otherwise noted; Electricals apply in both directions)

Characteristic	Symbol	Min	Typ	Max	Unit
*Peak Repetitive Blocking Current ( $V_D = V_{DRM} = V_{RRM}$ , Gate Open)	$I_{DRM}$ $I_{RRM}$	-	-	10	$\mu\text{A}$
		-	-	2.0	mA

# 2N6344

## Surface Mount – 600-800V

### Electrical Characteristics - ON (TC = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic	Symbol	Min	Typ	Max	Unit
†Peak On-State Voltage ( $I_{TM} = \pm 11$ A Peak; Pulse Width = 1 to 2 ms, Duty Cycle $\leq 2\%$ )	$V_{TM}$	-	1.3	1.55	V
Gate Trigger Current (Continuous dc) ( $V_D = 12$ Vdc, $R_L = 100 \Omega$ )					
Quadrant I: MT2(+), G(+)	Both	-	12	50	mA
Quadrant II: MT2(+), G(-)	2N6349 only	-	12	75	
Quadrant III: MT2(-), G(-)	Both	-	20	50	
Quadrant IV: MT2(-), G(+)	2N6349 only	-	35	75	
†MT2(+), G(+); MT2(-), G(-) $T_C = -40^\circ\text{C}$	-	-	-	100	
†MT2(+), G(-); MT2(-), G(+) $T_C = -40^\circ\text{C}$	-	-	-	125	
Gate Trigger Voltage (Continuous dc) ( $V_D = 12$ Vdc, $R_L = 100 \Omega$ )					
Quadrant I: MT2(+), G(+)	Both	-	0.9	2.0	V
Quadrant II: MT2(+), G(-)	2N6349 only	-	0.9	2.5	
Quadrant III: MT2(-), G(-)	Both	-	1.1	2.0	
Quadrant IV: MT2(-), G(+)	2N6349 only	-	1.4	2.5	
†MT2(+), G(+); MT2(-), G(-) $T_C = -40^\circ\text{C}$	-	-	-	2.5	
†MT2(+), G(-); MT2(-), G(+) $T_C = -40^\circ\text{C}$	-	-	-	3.0	
Gate Non-Trigger Voltage (Continuous dc) ( $V_D = \text{Rated } V_{DRM}$ , $R_L = 10 \text{ k}\Omega$ , $T_J = 100^\circ\text{C}$ ) †MT2(+), G(+); MT2(-), G(-); MT2(+), G(-); MT2(-), G(-)	$V_{GD}$	0.2	-	-	V
†Holding Current ( $V_D = 12$ Vdc, Gate Open) $T_C = 25^\circ\text{C}$ (Initiating Current = 200 mA) * $T_C = -40^\circ\text{C}$	$I_H$	-	6.0	40	mA
		-	-	75	
†Turn-On Time ( $V_D = \text{Rated } V_{DRM}$ , $I_{TM} = 11$ A, $I_{GT} = 120$ mA, Rise Time = 0.1 $\mu\text{s}$ , Pulse Width = 2 $\mu\text{s}$ )	$t_{gt}$	-	8	10	$\mu\text{s}$

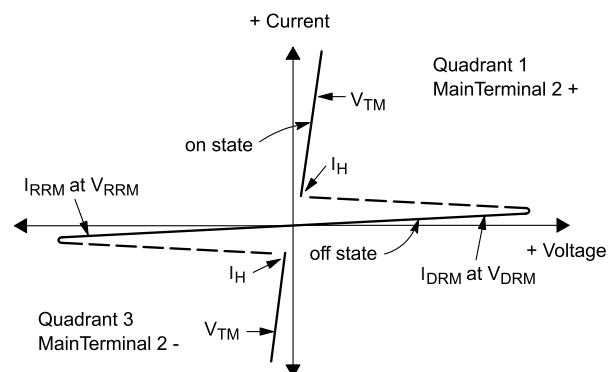
†Indicates JEDEC Registered Data.

### Dynamic Characteristics

Characteristic	Symbol	Min	Typ	Max	Unit
Critical Rate of Rise of Commutation Voltage ( $V_D = \text{Rated } V_{DRM}$ , $I_{TM} = 11$ A, Commutating $di/dt = 4.0$ A/ms, Gate Unenergized, $T_C = 80^\circ\text{C}$ )	$dv/dt(c)$	-	5.0	-	V/ $\mu\text{s}$

### Voltage Current Characteristic of Triacs (Bidirectional Device)

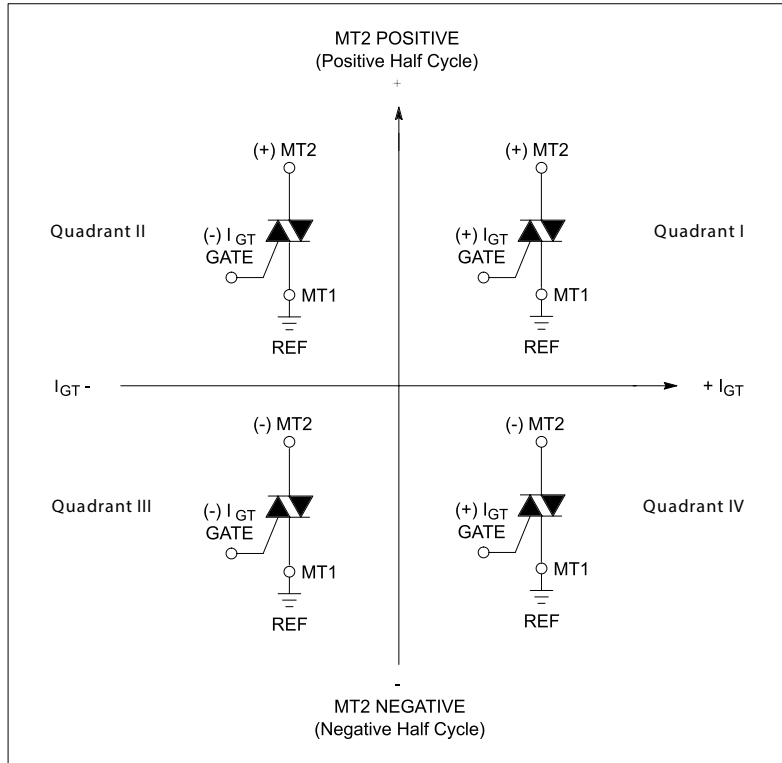
Symbol	Parameter
$V_{DRM}$	Peak Repetitive Forward Off State Voltage
$I_{DRM}$	Peak Forward Blocking Current
$V_{RRM}$	Peak Repetitive Reverse Off State Voltage
$I_{RRM}$	Peak Reverse Blocking Current
$V_{TM}$	Maximum On State Voltage
$I_H$	Holding Current



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## Quadrant Definitions for a Triac



All polarities are referenced to MT1.  
With in-phase signals (using standard AC lines) quadrants I and III are used.

## Ratings and Characteristic Curves

Figure 1. RMS Current Derating

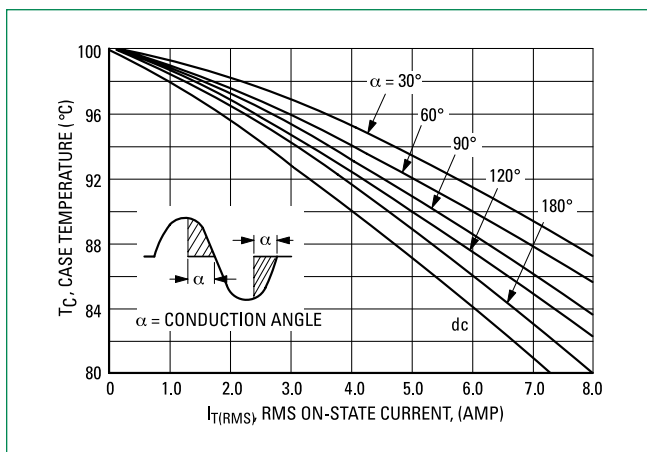
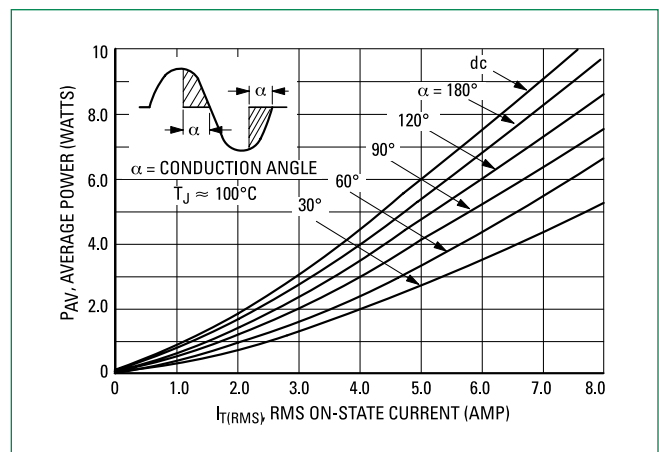


Figure 2. On-State Power Dissipation



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Figure 3. Typical Gate Trigger Voltage

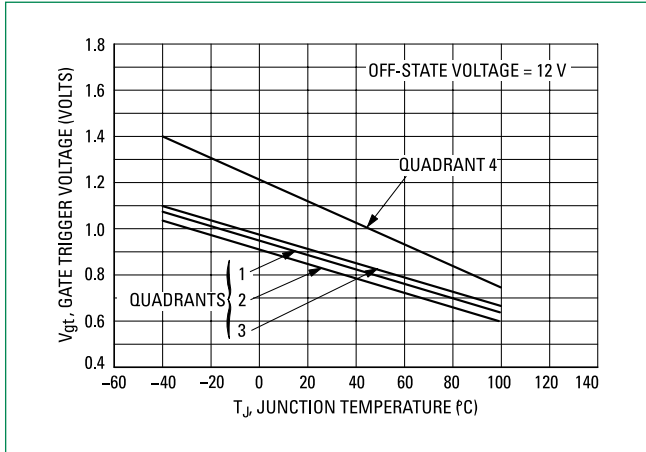


Figure 4. Typical Gate Trigger Current

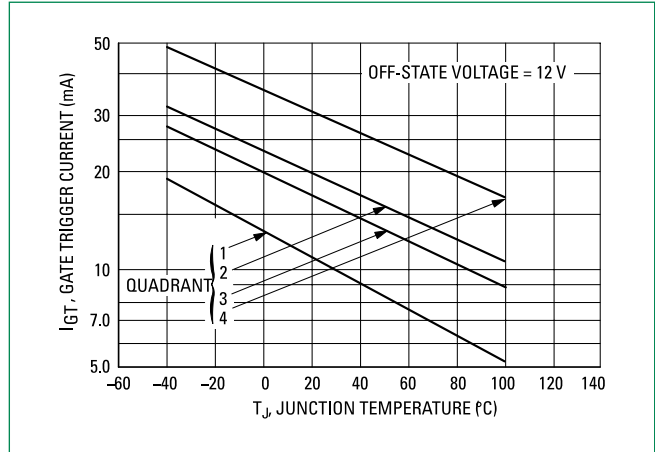


Figure 7. Maximum On-State Characteristics

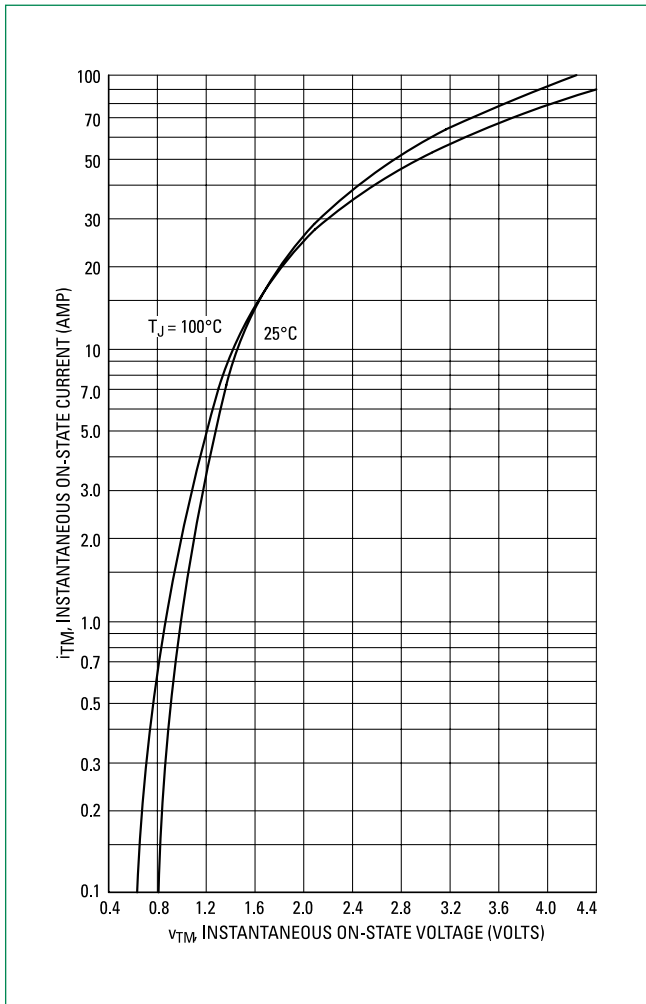


Figure 8. Typical Holding Current

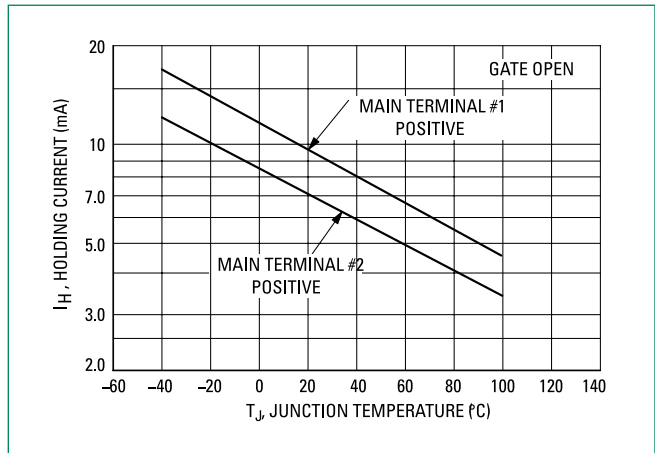
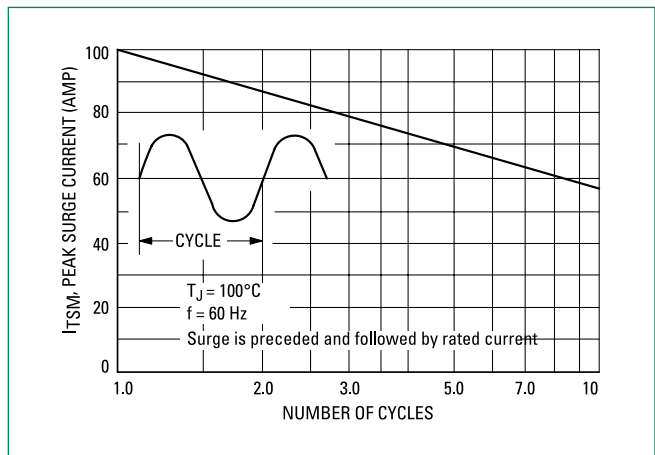


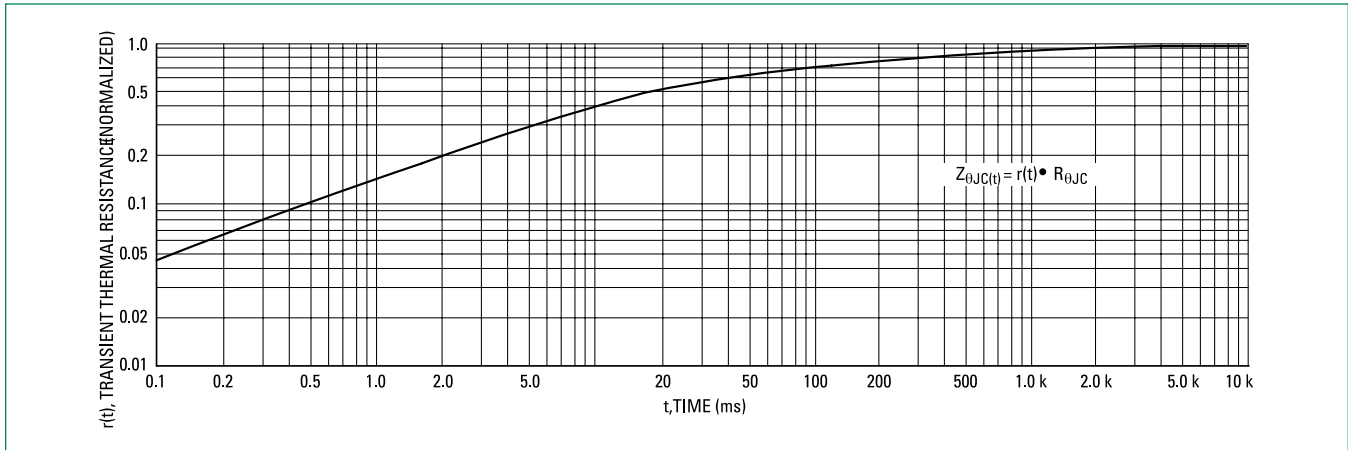
Figure 9. Maximum Allowable Surge Current



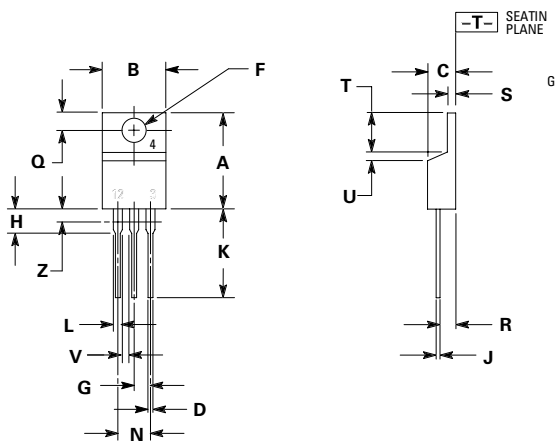
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Figure 10. Thermal Response

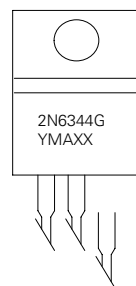
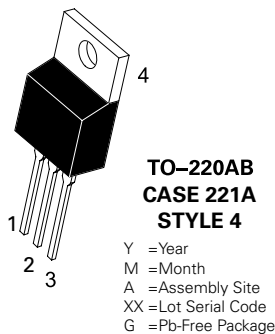


## Dimensions



Dim	Inches		Millimeters	
	Min	Max	Min	Max
A	0.590	0.620	14.99	15.75
B	0.380	0.420	9.65	10.67
C	0.178	0.188	4.52	4.78
D	0.025	0.035	0.64	0.89
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.41	2.67
H	0.110	0.130	2.79	3.30
J	0.018	0.024	0.46	0.61
K	0.540	0.575	13.72	14.61
L	0.060	0.075	1.52	1.91
N	0.195	0.205	4.95	5.21
Q	0.105	0.115	2.67	2.92
R	0.085	0.095	2.16	2.41
S	0.045	0.060	1.14	1.52
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	-	1.15	-
Z	-	0.080	-	2.04

## Part Marking System



1. Dimensioning And Tolerancing Per Ansi Y14.5m, 1982.
2. Controlling Dimension: Inch.
3. Dimension Z Defines A Zone Where All Body And Lead Irregularities Are Allowed.

## Ordering Information

Device	Package	Shipping†
2N6344	TO-220AB	1000 Units / Box
2N6344G	TO-220AB (Pb-Free)	

Pin Assignment	
1	Main Terminal 1
2	Main Terminal 2
3	Gate
4	Main Terminal 2

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